








	<h2>NSBC123JDXV6T1</h2>
	<p>Hersteller-Teilenummer: NSBC123JDXV6T1</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: TRANS 2NPN PREBIAS 0.5W SOT563</p> <p>Datenblätter:  NSBC123JDXV6T1.pdf</p> <p>RoHs Status: Enthält Blei / RoHS nicht konform</p> <p>Lagerzustand: New original, 600 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NSBC123JDXV6T1
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS 2NPN PREBIAS 0.5W SOT563
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	600 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SOT-563
Transistor-Typ	2 NPN - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	80 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	2.2k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Tape & Reel (TR)





NSBC123JDXV6T1 ist neu im Original, Suche NSBC123JDXV6T1 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSBC123JDXV6T1 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSBC123JDXV6T1: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSBC123EPDXV6T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p>NSBC123JPDP6T5G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.339W SOT963</p>	 <p>NSBC123EDXV6T1G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>	 <p>NSBC123EF3T5G AMI Semiconductor / ON Semiconductor TRANS PREBIAS DUAL NPN</p>
 <p>NSBC123EPDXV6T1 AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p>NSBC123JDP6T5G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.339W SOT963</p>	 <p>NSBC123JPDXV6T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p>NSBC123JPDXV6T1 AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>

heiße Teile

Mehr

 08051A680FAT4A	 AOT20C60P	 BF2012-F2R4DAAT/LF	 C3216X5R1H106K160AB	 CDSOD323-T12S
 MLF2012DR82JT000	 NSB1706DMW5T1G	 NSB4904DW1T1G	 NSB8JT-E3/31	 NSB9435T1
 NSB9435T1G	 NSBA114EDP6T5G	 NSBA114EDXV6T1	 NSBA114YDXV6T1	 NSBA123JDXV6T1
 NSBA123JDXV6T1G	 NSBA123JDXV6T5G	 NSBA143TDXV6T1G	 NSBA144EDP6T5G	 NSBC114EDXV6T1
 NSBC114EDXV6T1G	 NSBC114EPDXV6T1G	 NSBC114EPDXV6T5	 NSBC114TDXV6T1	 NSBC114YDP6T5G
 NSBC114YDXV6T1	 NSBC114YDXV6T1G	 NSBC114YDXV6T5	 NSBC114YDPDXV6T1	 NSBC115EDXV6T1
 NSBC123JPDXV6T1	 NSBC123JPDXV6T1G	 NSBC124EPDXV6T1	 NSBC124EPDXV6T5	 NSBC124XPDXV6T1
 NSBC143EDXV6T5	 NSBC143ZPDXV6T1G	 NSBC143ZPDXV6T5	 NSBC144EDXV6T1	 NSBC144EDXV6T1G
 NSBC144EDXV6T5	 NSBC144EDXV6T5G	 NSBC144EPDXV6T1	 NSBC144EPDXV6T1G	 NX5L2750CGU
 PK110F80	 PX3511BDDG	 QM3012NB	 ST72F561K9	 TL7702BIDR

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